

## Dual Common Cathode diodes Power Module

$V_{RRM} = 1700V$   
 $I_C = 400A @ T_c = 55^\circ C$



### Application

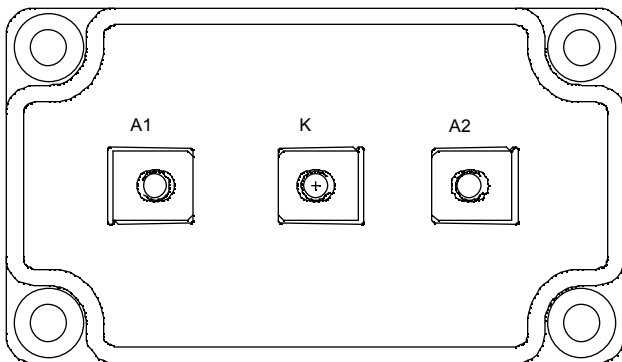
- Uninterruptible Power Supply (UPS)
- Induction heating
- Welding equipment
- High speed rectifiers

### Features

- Ultra fast recovery times
- Soft recovery characteristics
- High blocking voltage
- High current
- Low leakage current
- Very low stray inductance
  - Symmetrical design
  - M5 power connectors
- High level of integration


### Benefits

- Outstanding performance at high frequency operation
- Low losses
- Low noise switching
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- RoHS Compliant



### Absolute maximum ratings

Symbol	Parameter	Max ratings	Unit	
$V_R$	Maximum DC reverse Voltage	1700	V	
$V_{RRM}$	Maximum Peak Repetitive Reverse Voltage			
$I_{F(AV)}$	Maximum Average Forward Current	Duty cycle = 50%	$T_c = 25^\circ C$	A
			$T_c = 55^\circ C$	
$I_{F(RMS)}$	RMS Forward Current	500		
$I_{FSM}$	Non-Repetitive Forward Surge Current	$T_j = 25^\circ C$	1500	

 **CAUTION:** These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on [www.microsemi.com](http://www.microsemi.com)

All ratings @  $T_j = 25^\circ\text{C}$  unless otherwise specified

**Electrical Characteristics**

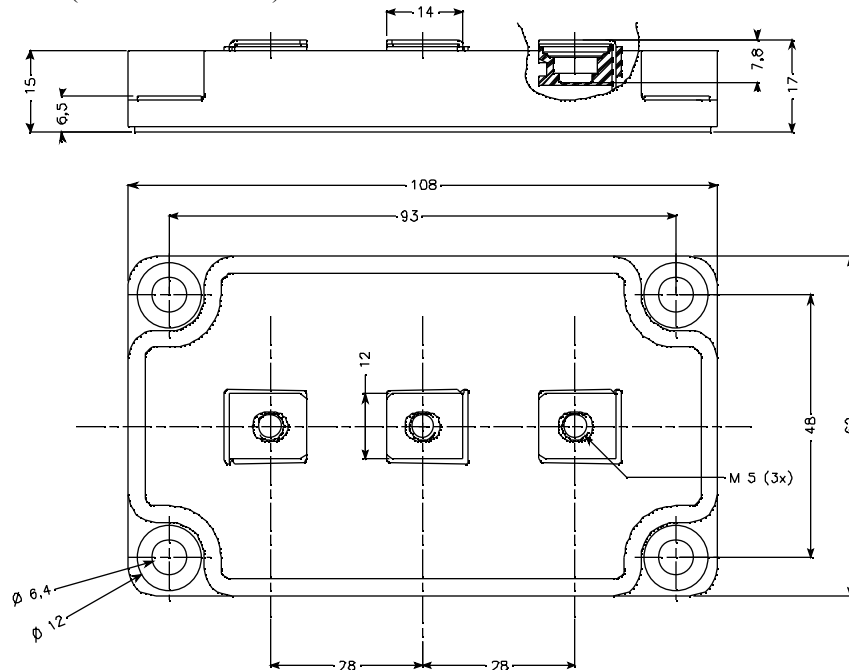
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
$V_F$	Diode Forward Voltage	$I_F = 400\text{A}$	$T_j = 25^\circ\text{C}$		2.2	2.5	V
			$T_j = 125^\circ\text{C}$		2.1		
$I_{RM}$	Maximum Reverse Leakage Current	$V_R = 1700\text{V}$	$T_j = 25^\circ\text{C}$			750	$\mu\text{A}$
			$T_j = 125^\circ\text{C}$			1000	

**Dynamic Characteristics**

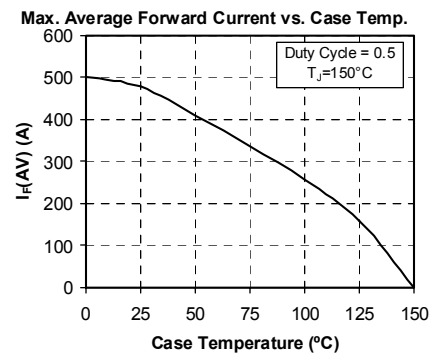
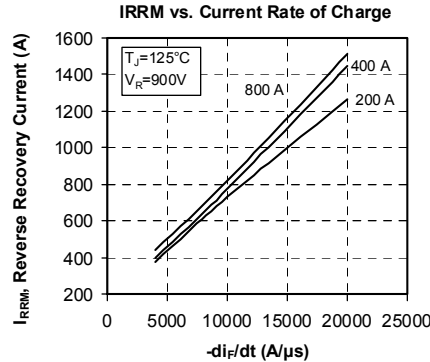
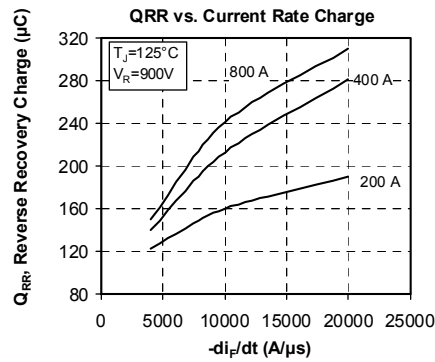
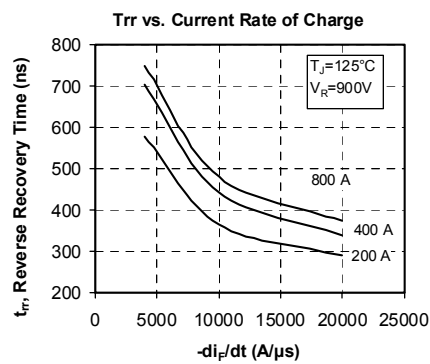
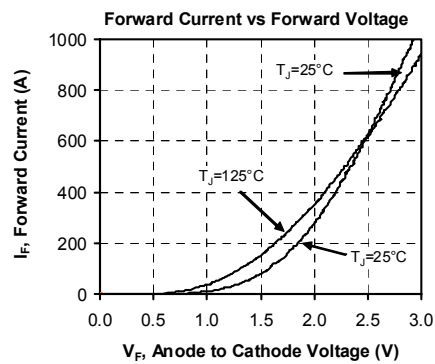
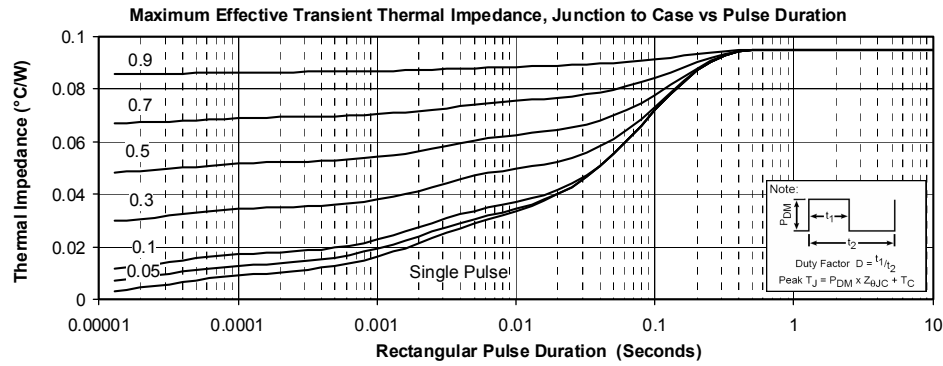
Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$t_{rr}$	Reverse Recovery Time	$I_F = 400\text{A}$ $V_R = 900\text{V}$ $di/dt = 4000\text{A}/\mu\text{s}$	$T_j = 25^\circ\text{C}$		572	ns
			$T_j = 125^\circ\text{C}$		704	
$Q_{rr}$	Reverse Recovery Charge		$T_j = 25^\circ\text{C}$		80	$\mu\text{C}$
			$T_j = 125^\circ\text{C}$		140	
$I_{RRM}$	Reverse Recovery Current		$T_j = 25^\circ\text{C}$		280	A
			$T_j = 125^\circ\text{C}$		400	

**Thermal and package characteristics**

Symbol	Characteristic	Min	Typ	Max	Unit	
$R_{thJC}$	Junction to Case Thermal Resistance			0.095	$^\circ\text{C}/\text{W}$	
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case $t = 1\text{ min}$ , $I_{isol} < 1\text{mA}$ , 50/60Hz	3500			V	
$T_J$	Operating junction temperature range	-40		150	$^\circ\text{C}$	
$T_{STG}$	Storage Temperature Range	-40		125		
$T_C$	Operating Case Temperature	-40		100		
Torque	Mounting torque	To heatsink	M6	3	5	N.m
		For terminals	M5	2	3.5	
Wt	Package Weight			280	g	

**SP6 Package outline** (dimensions in mm)


## Typical Performance Curve



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